

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:		)
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	Toshiki Makimoto, et al.	)
		)
Serial No.:	10/516,380	) Art Unit
		) 2811
Filed:	November 30, 2004	)
		)
Confirmation No.:	2860	)
		)
For:	P-TYPE NITRIDE SEMICONDUCTOR	)
	STRUCTURE AND BIPOLAR TRANSISTOR	)
		)
Examiner:	Toshiki Makimoto	)

AUTHORIZATION TO CHARGE DEPOSIT ACCOUNT

Commissioner for Patents  
PO Box 1450  
Alexandria, Virginia 22313-1450

Sir:

The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 23-3178.

X Any additional filing fees required under 37 CFR § 1.16.

X Any patent application processing fees under 37 CFR § 1.17.

Dated this 29<sup>th</sup> day of November 2006.

Respectfully submitted,

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